









 	<h2 style="color: red;">FQU12N20TU</h2> <p>Hersteller-Teilenummer: FQU12N20TU</p> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 200V 9A IPAK</p> <p>Datenblätter:  FQU12N20TU.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 12582 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQU12N20TU
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 200V 9A IPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	12582 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-251-3 Short Leads, IPak, TO-251AA
Supplier Device-Gehäuse	I-Pak
Verlustleistung (max)	2.5W (Ta), 55W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	200V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	9A (Tc)
Rds On (Max) @ Id, Vgs	280 mOhm @ 4.5A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	23nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	910pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tube



















































FQU12N20TU ist neu im Original, Suche FQU12N20TU Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQU12N20TU Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQU12N20TU: Info@Y-IC.com

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heiße Teile

Mehr

 FQU10N20	 FQU10N20C	 FQU10N20CTU	 FQU10N20CTU	 FQU10N20L
 FQU11P06	 FQU11P06TU	 FQU11P06TU	 FQU12N20	 FQU12N20L
 FQU12N20TU	 FQU13N06	 FQU13N06L	 FQU13N06LTU	 FQU13N06LTU
 FQU13N10	 FQU13N10L	 FQU13N10LTU	 FQU13N10LTU	 FQU17N08L
 FQU17P06	 FQU17P06TU	 FQU17P06TU	 FQU1N50C	 FQU1N60B
 FQU1N60C	 FQU1N60CTU	 FQU1N60CTU	 FQU1N80TU	 FQU1N80TU
 FQU20N06	 FQU20N06L	 FQU20N06LTU	 FQU20N06LTU	 FQU2N50B
 FQU2N50BTU	 FQU2N50BTU	 FQU2N60/SSU2N60	 FQU2N60A	 FQU2N60B
 FQU2N60C	 FQU2N60CTU	 FQU2N60CTU	 FQU2N65C	 FQU2N90TU
 FQU2N90TU	 FQU30N06L	 FQU3N40TU	 FQU3N40TU	 FQU3N50C

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